

## 20V N-Channel Enhancement Mode MOSFET

### Description

The NP2016DR uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

### General Features

- ◆  $V_{DS} = 20V$ ,  $I_D = 16A$   
 $R_{DS(ON)}(Typ.) = 9m\Omega$  @  $V_{GS} = 4.5V$   
 $R_{DS(ON)}(Typ.) = 11.5m\Omega$  @  $V_{GS} = 2.5V$
- ◆ High power and current handling capability
- ◆ Lead free product is acquired
- ◆ Surface mount package

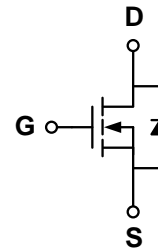
### Application

- ◆ PWM applications
- ◆ Load switch

### Package

- ◆ DFN2\*2-6L-B

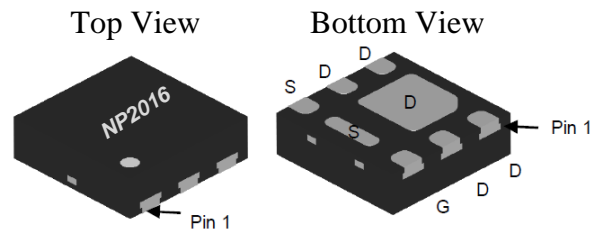
### Schematic diagram



### Marking and pin assignment

#### DFN2\*2-6L-B

(Thickness 0.55mm)



NP----Natlinear Power  
 2016----NP2016



### Ordering Information

Part Number	Storage Temperature	Package	Devices Per Reel
NP2016DR-G	-55°C to +150°C	DFN2*2-6L-B	4000

### Absolute Maximum Ratings (TA=25°C unless otherwise noted)

parameter	symbol	limit	unit
Drain-source voltage	$V_{DS}$	20	V
Gate-source voltage	$V_{GS}$	±12	V
Drain current-continuous <sup>a</sup> @ $T_j = 125^\circ C$ -pulse $d^b$	$I_D$	16	A
	$I_{DM}$	64	A
Drain-source Diode forward current	$I_S$	16	A
Maximum power dissipation	$P_D$	2.2	W
Operating junction Temperature range	$T_j$	-55—150	°C

**Electrical Characteristics** (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
<b>OFF Characteristics</b>						
Drain-source breakdown voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-body leakage	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 12V$	-	-	$\pm 100$	nA
<b>ON Characteristics</b>						
Gate threshold voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	0.7	0.9	V
Drain-source on-state resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=16A$	-	9	12	m $\Omega$
		$V_{GS}=2.5V, I_D=12A$	-	11.5	14	
Forward transconductance	gfs	$V_{GS}=5V, I_D=16A$	-	10	-	S
<b>Dynamic Characteristics</b>						
Input capacitance	$C_{ISS}$	$V_{DS}=10V, V_{GS}=0V$ $f=1.0MHz$	-	900	-	pF
Output capacitance	$C_{OSS}$		-	220	-	
Reverse transfer capacitance	$C_{RSS}$		-	100	-	
<b>Switching Characteristics</b>						
Turn-on delay time	$t_{D(ON)}$	$V_{DD}=10V$ $I_D=16A$ $V_{GEN}=4.5V$ $R_{GEN}=6\Omega$	-	10	20	ns
Rise time	$t_r$		-	11	25	
Turn-off delay time	$t_{D(OFF)}$		-	35	70	
Fall time	$t_f$		-	30	60	
Total gate charge	Qg	$V_{DS}=10V, I_D=16A$ $V_{GS}=4.5V$	-	12	15	nC
Gate-source charge	Qgs		-	2.3	-	
Gate-drain charge	Qgd		-	1	-	
<b>DRAIN-SOURCE DIODE CHARACTERISTICS</b>						
Diode forward voltage	$V_{SD}$	$V_{GS}=0V, I_S=16A$	-	-	1.2	V

**Notes:**

- surface mounted on FR4 board,  $t \leq 10sec$
- pulse test: pulse width  $\leq 300\mu s$ , duty  $\leq 2\%$
- guaranteed by design, not subject to production testing

**Thermal Characteristics**

Thermal Resistance junction-to ambient	Rth JA	58	$^{\circ}C/W$
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## Typical Performance Characteristics

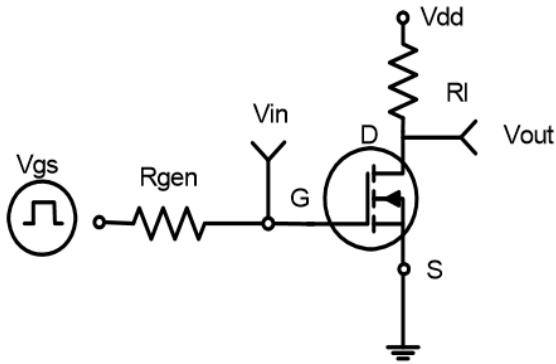


Figure 1: Switching Test Circuit

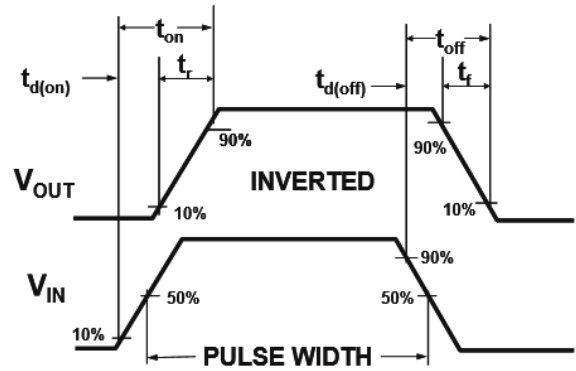


Figure 2: Switching Waveforms

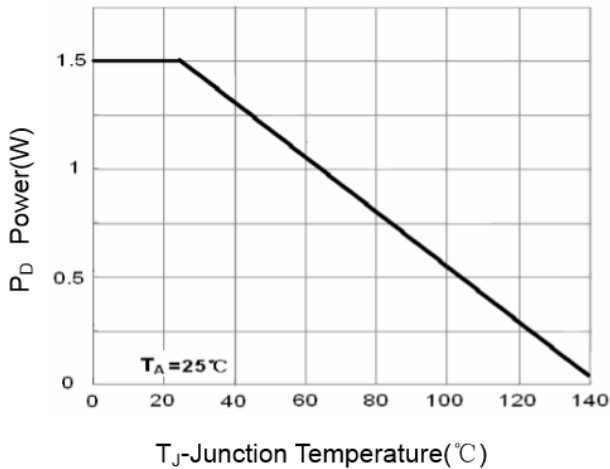


Figure 3 Power Dissipation

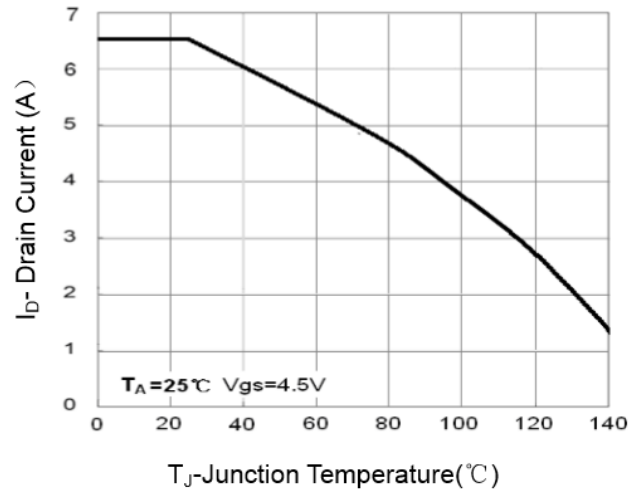


Figure 4 Drain Current

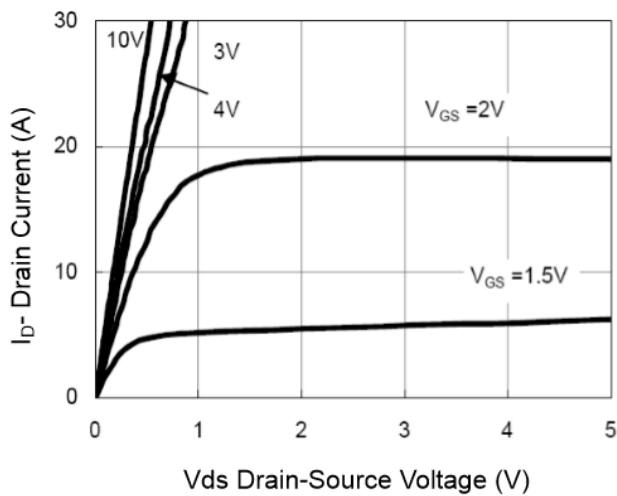


Figure 5 Output Characteristics

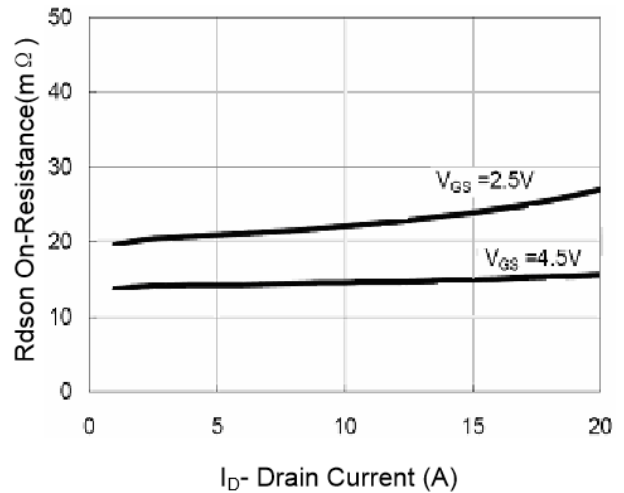


Figure 6 Drain-Source On-Resistance

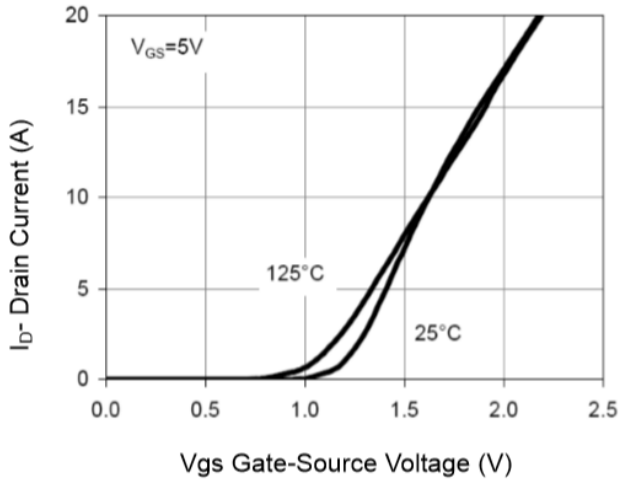


Figure 7 Transfer Characteristics

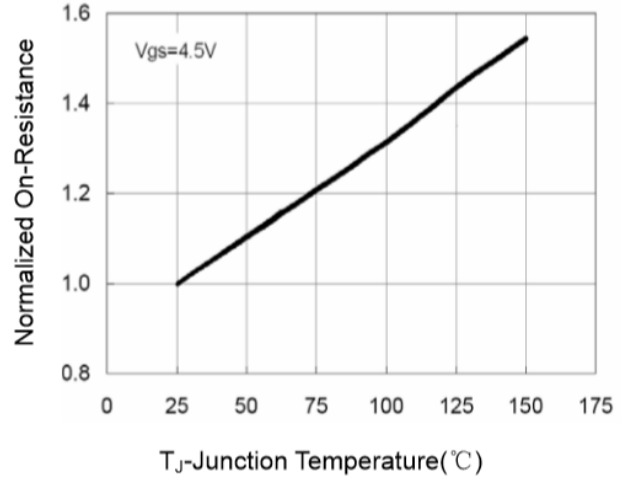


Figure 8 Drain-Source On-Resistance

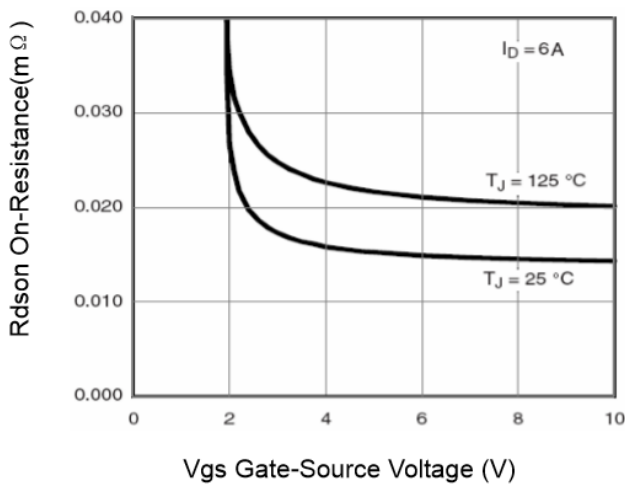


Figure 9 Rdson vs Vgs

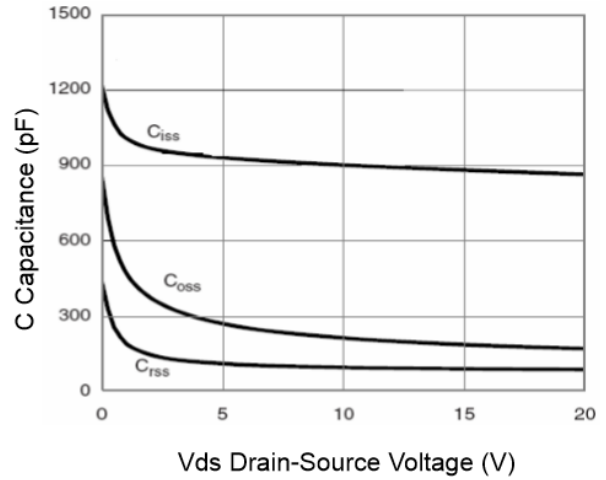


Figure 10 Capacitance vs Vds

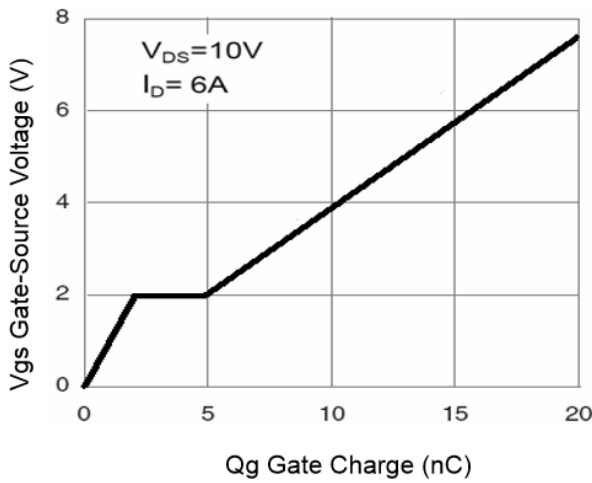


Figure 11 Gate Charge

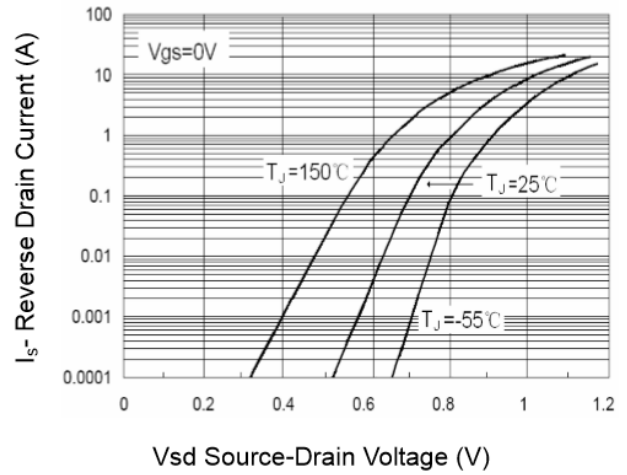


Figure 12 Source- Drain Diode Forward

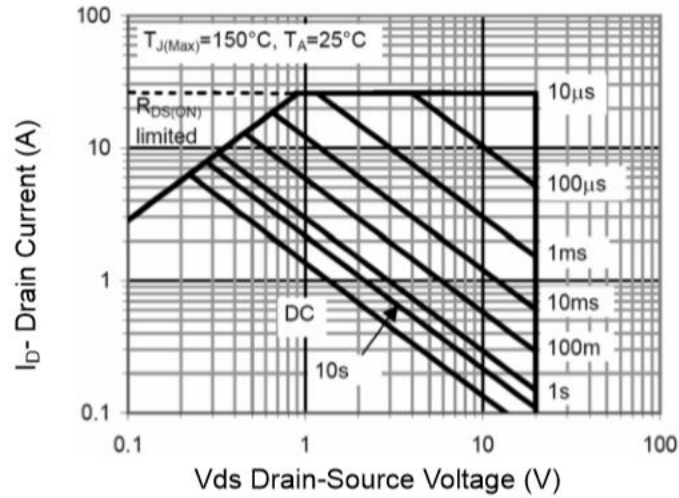


Figure 13 Safe Operation Area

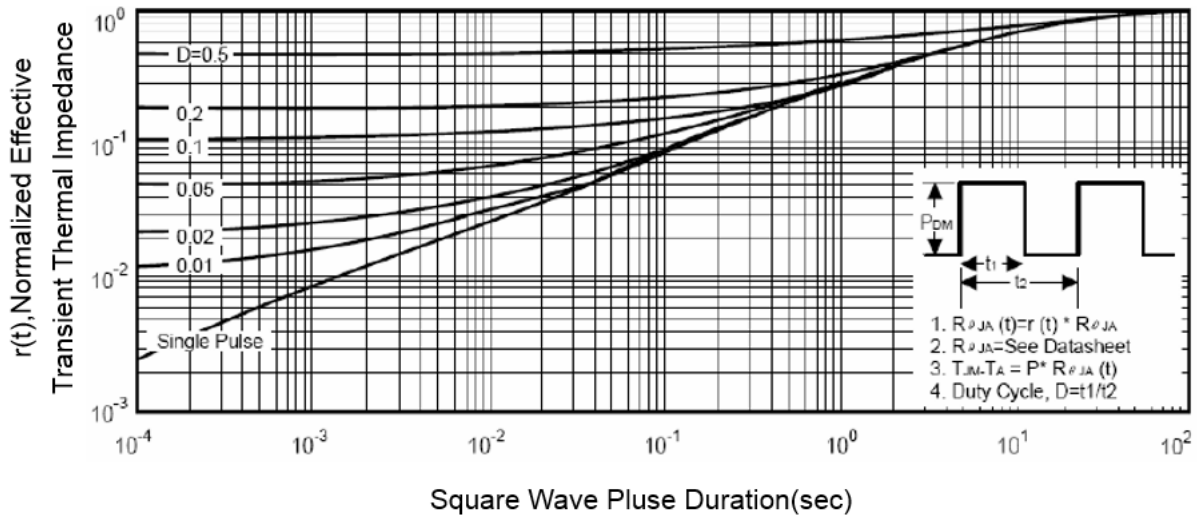
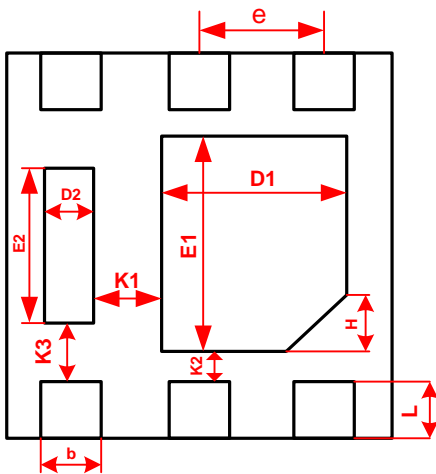
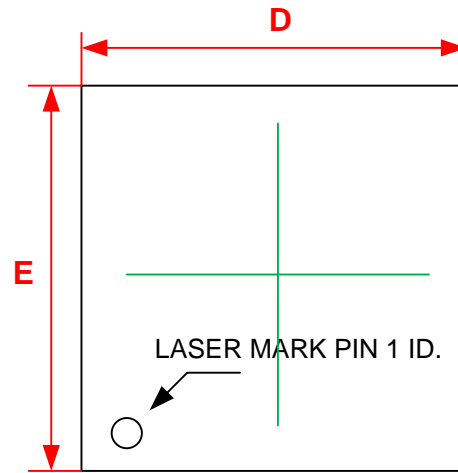
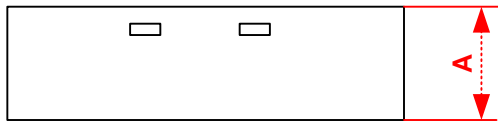
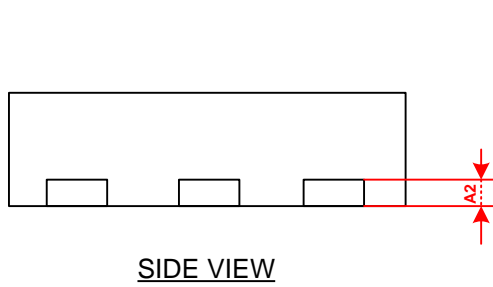


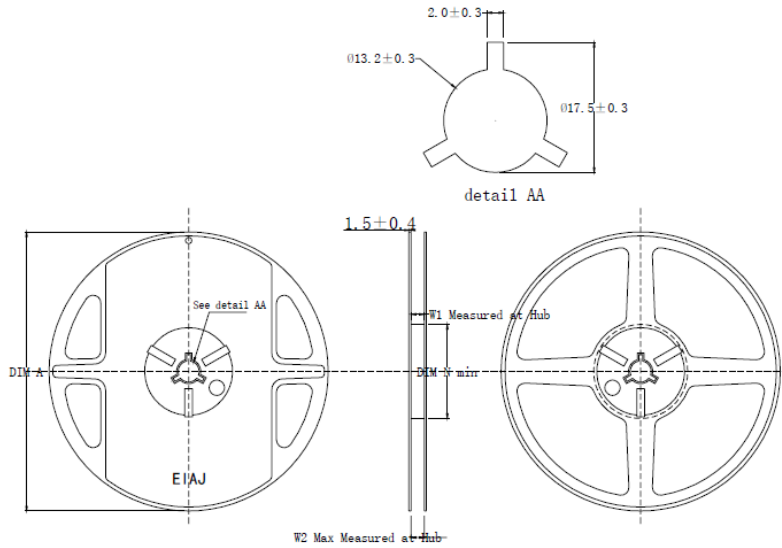
Figure 14 Normalized Maximum Transient Thermal Impedance

## Package Information

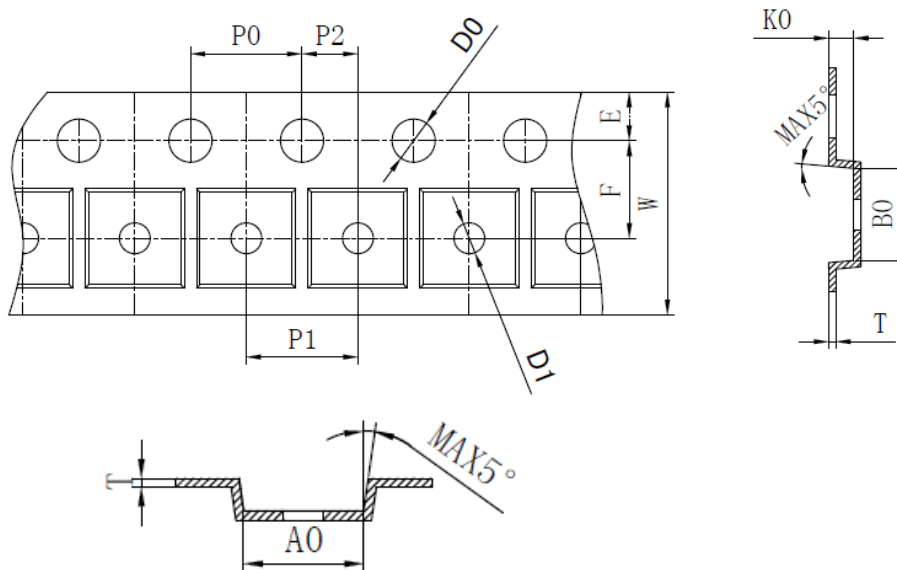
- DFN2\*2-6L-B



Common Dimension (mm)			
PKG	DFN2020-6L-B		
SYMBOL	MIN.	MON.	MAX.
A	0.527	0.552	0.577
A2		0.127REF	
b	0.25	0.30	0.35
D	1.90	2.00	2.10
E	1.90	2.00	2.10
D1	0.85	0.95	1.05
E1	1.05	1.15	1.25
D2	0.20	0.25	0.30
E2	0.69	0.79	0.89
e	0.55	0.65	0.75
H	0.25	0.30	0.35
K1	0.25MIN		
K2	0.15MIN		
K3	0.20MIN		
L	0.20	0.25	0.30

**Tape and Reel**


PRODUCT SPECIFICATIONS				
TYPE WIDTH	$\phi A$	$\phi N$	W1 (Min)	W2 (Max)
8MM	$178 \pm 2.0$	$60 \pm 1.0$	8.4	11.4
12MM	$178 \pm 2.0$	$60 \pm 1.0$	12.4	15.4



SYMBOL	A0	B0	K0	P0	P1	P2
SPEC	$2.20 \pm 0.05$	$2.20 \pm 0.05$	$0.75 \pm 0.10$	$4.00 \pm 0.10$	$4.00 \pm 0.10$	$2.00 \pm 0.05$
SYMBOL	T	E	F	D0	D1	W
SPEC	$0.20 \pm 0.03$	$1.75 \pm 0.10$	$3.50 \pm 0.05$	$1.55 \pm 0.05$	$1.00^{+0.10}_{-0}$	$8.00^{+0.20}_{-0.10}$